

## TH-YDS2/24D4006——Ultra-thin Opto-MOS module

### 概述 Features

- 厚度 6.2mm SSR
- 负载电流至4A
- 击穿电压60V
- 介质耐压3000V
- 带工作状态显示
- 带导轨快连接安装
- 符合RoHS
- Thickness 6.2mm SSR
- Load current up to 4A
- Breakdown voltage 60V
- Dielectric strength 3000V
- Operating display
- Rail fast mount
- RoHS compliant



### 应用 Applications

- 交通信号控制 Traffic signals control
- 测试设备 Measuring instruments
- 工业控制 Industrial control

### 打印标志 Marking information

Part number	Package	Marking
TH-YDS2/24D4006	导轨快速安装	TH-YDS2 24D4006

### 极限值 Absolute maximum ratings

(Ta=25°C)

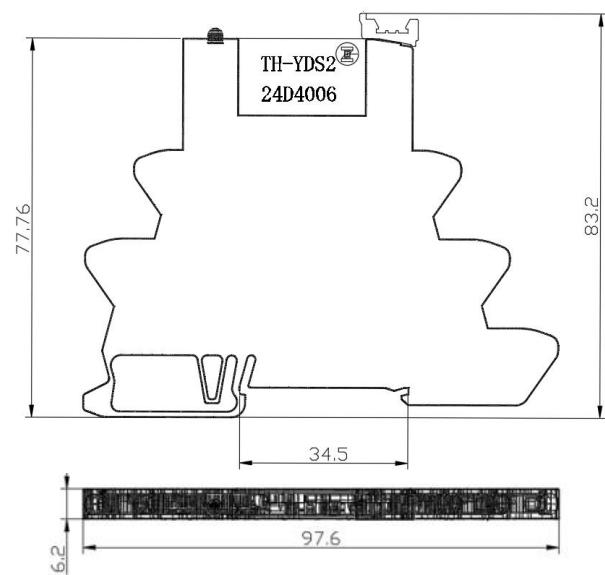
特性参数/Parameter		符号 /Symbol	测试条件/Test condition	最小值 /Min.	典型值 /Typ.	最大值 /Max.	单位 /Unit
输入端 /Input	工作电压/Operating voltage	V <sub>in</sub>		19	24	28.8	V
输出端 /Output	击穿电压/ Breakdown voltage	BV <sub>DSS</sub>		60			V
	功耗/Power dissipation	p <sub>out</sub>			2	2.5	W
	额定电流/On-state current	I <sub>L</sub>	V <sub>in</sub> =24V			4	A
	峰值电流/Peak current	I <sub>peak</sub>	100 ms (1shot), VL = DC		7		A
介质耐压/Dielectric strength *		V <sub>ISO</sub>	I <sub>ISO</sub> ≤0.3mA	3000			V <sub>rms</sub>
工作温度/Operating temperature		T <sub>opr</sub>		-30		85	°C
储存温度/Storage temperature		T <sub>stg</sub>		-40		125	°C

“\*” : RH =40 to 60%, T=20~30°C, AC for 1 minute.

## 电参数 Electrical parameters

特性参数/Parameter		符号/Symbol	测试条件/Test condition	最小值/Min.	典型值/Typ.	最大值/Max.	单位/Unit
输入端/Input	输入电流/Input current	$I_{in}$	$V_{in}=V_{in}+20\%$		14	18	mA
输出端/Output	断态泄漏电流/Output off-state leakage current	$I_{Leak}$	$V_o=60V$			10	$\mu A$
耦合特性 /Transfer characteristics	接通电压/Turn on voltage	$V_{on}$			8	18	V
	关断电压/Must release voltage	$V_{off}$		1.2			V
	导通电阻/Output on-state resistance	$R_{on}$	$I_{in}=10mA$ , $I_d=1.6A$		45	100	$m\Omega$
	导通时间/Turn on time	$T_{on}$	$I_{in}=10mA$ , $I_d=1.6A$			5	ms
	关断时间/Turn off time	$T_{off}$	$I_{in}=10mA$ , $I_d=1.6A$			2	ms
	电容/I/O capacitance	C				3	pF

## 外形尺寸 Outline dimension :mm



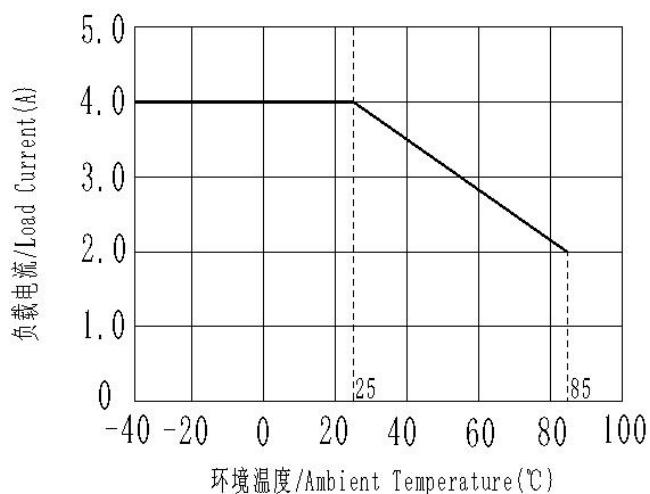
## 订货信息 Ordering information

订货信息/Ordering information							
	TH	Y	DS	2	24D	400	6
超薄型模块 Ultra-thin module							
公司商标代号 Company symbol							
直流 MOS 输出 SSR:MOS DC Output SSR							
封装 Package: 2: SIP4							
输入端电压型 Voltage driving: 24D-24Vdc							
负载电流 Load current: 400-4A							
击穿电压 $BV_{dss}$ : 6—60V							

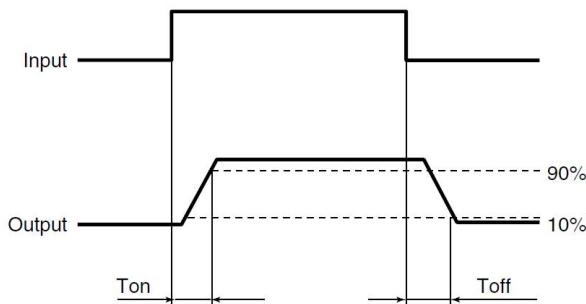
## 特性曲线 Characteristic data

### 1. 负载电流与环境温度关系曲线

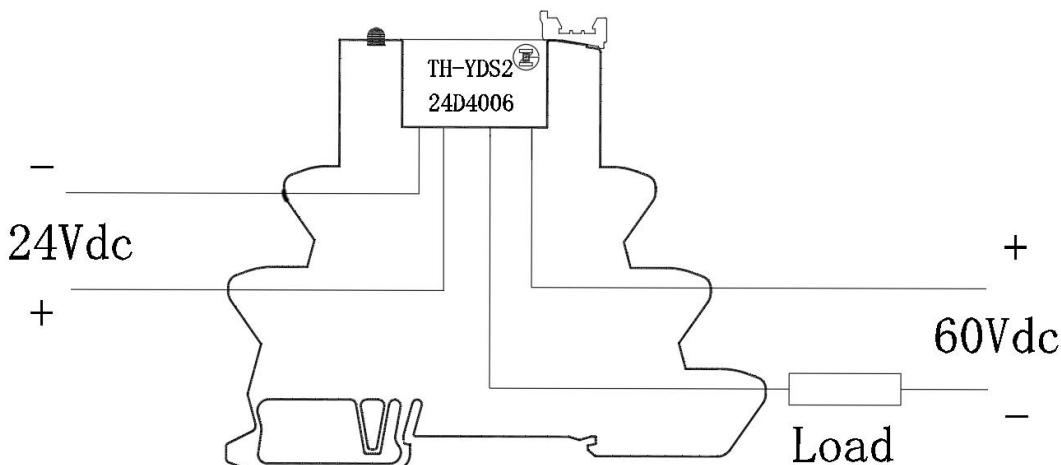
Load current VS. ambient temperature



## 接通和关断时间关系 Turn on and turn off time



## 接线图 Wiring diagram



## 注意事项 Notes

a) 工作环境温度超过 25℃时请降额使用。参见特性曲线 1。

When ambient temperature is above 25°C, the load current must be reduced. (see characteristic data)

b) 继电器接线时，务必保证输入端极性的正确，以免损坏继电器。

Ensuring the polarity is correct when connecting the input lines, otherwise the wrong connection will damage the relay.

## 关于防静电对策 Cautions for static electricity

a. 操作 MOS 输出继电器的作业人员，请穿戴防静电工作服，通过  $500k\Omega \sim 1M\Omega$  左右的保护电阻，实施人体接地。Employees handling relays should wear anti-static clothes and should be grounded through protective resistance of  $500k\Omega$  to  $1M\Omega$ .

- b. 请在作业台上装有带导电性的金属板或具有防静电的专用板，并对测量仪器和治具等实施接地。A conductive metal sheet should be placed over the work table. Measuring instruments and jigs should be grounded.
- c. 组装时使用的设备等也应正确的接地。Devices and equipment used in assembly should also be grounded.
- d. 对印刷电路板和机器进行包装时，请避免使用发泡苯乙烯、聚乙烯等带电性的高分子材料。When packing printed circuit boards and equipment, avoid using high-polymer materials such as foam styrene, plastic, and other materials which carry an electrostatic charge.
- e. 对MOS输出继电器进行储存和搬运时，请在不易产生静电的环境(例如湿度45~60%)中通过导电性包装材料进行保护。When storing or transporting relays, the environment should not be conducive to generating static electricity (for instance, the humidity should be between 45 and 60%), and relays should be protected using conductive packing materials.